

Precision, Adjustable Shunt Regulator (600mV Reference)



FEATURES

- 600mv low voltage reference
- 35ppm low temperature coefficient
- ±6mV initial accuracy
- High PSRR: 45dB at 300kHz
- Better line regulation: 1mV (V_{IN} from 2.2V to 18V)
- Low supply current: 90µA
- Open drain output
- Directly drives optocouplers
- Industrial temperature range of -40°C to 85°C
- RoHS-compliant 5-lead TSOT23 package

APPLICATION

- SMPS control loop
- Low temperature coefficient voltage reference
- Power management
- Replaces zener diodes
- Isolated DC-to-DC converters
- Network, telecom and cellular base station
- Adjustable voltage reference

DESCRIPTION

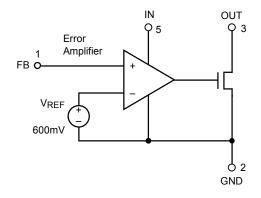
The CAT102 is a low-voltage reference and amplifier. Designed for the control loop of low-voltage power supplies, the reference voltage has been designed for 600mV. Over a junction temperature from -40°C to 105°C, the reference voltage is within 8mV of the nominal 600mV. In addition, the error amplifier output and the supply voltage pin (IN) are on separate pins.

Power supply rejection is a high 45dB at 300kHz. The output, OUT, can sink 20mA at a maximum saturation voltage of 250mV.

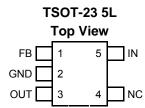
When combined with an optocoupler, the CAT102 can be used as an error amplifier that controls the feedback loop in isolated low-output voltage switching power supplies.

For Ordering Information details, see page 7.

FUNCTIONAL DIAGRAM



PIN CONFIGURATION



PIN DESCRIPTION

Pin Name	Function	
FB	Inverting input to error amplifier	
GND	Ground	
OUT	Output of error amplifier. Source & sink current capability is 20mA.	
NC	No connection	
IN	Positive supply	



ABSOLUTE MAXIMUM RATINGS(1)

Parameters	Ratings	Units
V _{IN} Voltage	20	V
OUT Voltage	20	V
FB Voltage	20	V
V _{IN} , OUT, FB Current	50	mA
Operating Junction Temperature (10s)	150	°C
Lead Soldering Temperature (10s)	260	°C
Storage Temperature Range	-65 to +150	°C

ELECTRICAL CHARACTERISTICS

Electrical characteristics are guaranteed over the full operating temperature range of -40°C to +85°C with a junction temperature from -40°C to +105°C unless otherwise specified. Ambient temperature must be de-rated based upon power dissipation and package thermal characteristics. Unless otherwise stated, test conditions are $V_{IN} = 3V$, FB = OUT, $I_{OUT} = 1mA$.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{IN}	Supply Voltage Range		2.2		18	V
I _{IN}	Quiescent Supply Current	V _{OUT} =1V		90	500	μA
V_{FB}	ED Throshold Deference Voltage	T _J = 25° C	594	600	606	\ /
	FB Threshold Reference Voltage	-40°C < T _J < 105°C	592		608	mV
	Line Regulation	$V_{IN} = 2.2V \text{ to } V_{IN} = 18V$		0.5	1	mV
	Load Regulation	I _{OUT} = 1mA to 10mA		3	8	mV
T _{CREF}	Reference Temperature Deviation	-40°C < T _J < 105°C		35	50	ppm/°C
I _{FB}	FB Input Current		-500		500	nA
PSRR	Reference Power Supply Rejection	Frequency = 300kHz	35	65		dB
A _V	Error Amplifier Open Loop Gain	$I_{OUT} = 2mA, V_{OUT} = 1V$	60	80		dB
BW	Unity Gain Frequency	$I_{OUT} = 2mA, V_{OUT} = 1V$	1	2		MHz
V _{OUT}	Output Saturation voltage	I_{OUT} = 20mA, V_{FB} = HIGH		130	250	mV
TRANSC	Output Transconductance	I _{OUT} = 1mA to 20mA		2.5		mA/mV
I _{LEAK}	Output Leakage Current	V _{OUT} = 16V, V _{FB} = 0		20	400	nA
I _{OUT(MAX)}	Maximum Output Current	V _{OUT} = 0.3V	20			mA

Notes

Doc. No. MD-4007 Rev. N

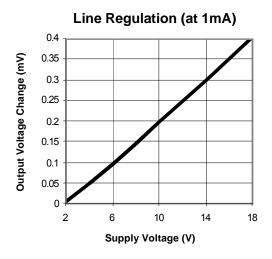
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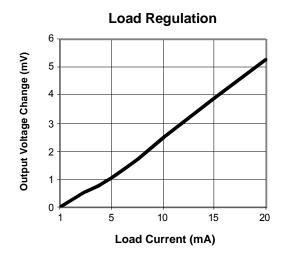
(2) Thermal Characteristics (Θ_{JA}) of TSOT-23 5-lead: 255°C/W

⁽¹⁾ These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolongued time periods may affect device reliability. All voltages are with respect to ground.

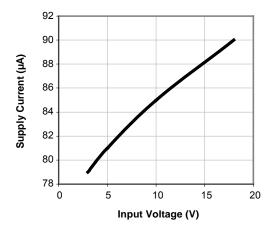


TYPICAL PERFORMANCE CHARACTERISTICS

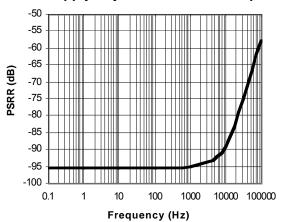




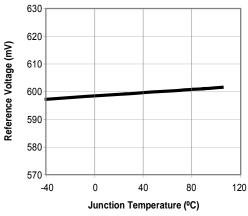
Supply current vs. Input Voltage

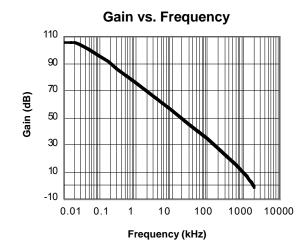


Power-Supply Rejection Ratio vs. Frequency











APPLICATIONS INFORMATION

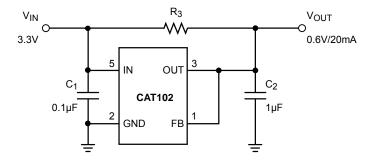
The CAT102 adjustable shunt regulator features isolated supply inputs and outputs, ideal for isolated power-supply applications using an optocoupler in the feedback path. The CAT102 sinks 20mA with V_{OUT} at 0.3V. The wide input supply range allows the device to operate from 2.2V to 18V. The CAT102 compares the FB input to a precision 600mV reference. If the FB input is low, the OUT pin sinks no current. If FB rises above 600mV, the OUT pin sinks up to 20mA.

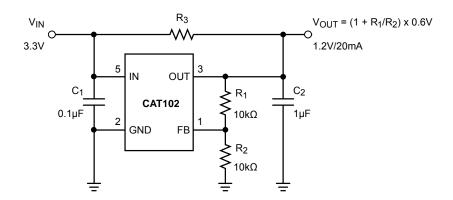
Figure 1 shows the CAT102 configured as a shunt regulator. To generate an output voltage of 0.6V, the FB pin has to be directly connected to the OUT pin. A 1.0µF capacitor from OUT to GND is recommended when the output voltage is 0.6V. A resistor-divider connected from OUT to GND is used to produce a higher output voltage as set by the following equation:

$$V_{OUT} = (1 + R_1/R_2) \times 0.6V$$

The current limit can be adjusted by using a resistor R3 connected between the IN and OUT pins. For example, a 3.3V supply V_{IN} is associated with R_3 = 135 Ω , and a 10V supply works best with R_3 = 470 Ω . The CAT102 shunt regulator is limited to low-current applications with the OUT pin capable of sinking up to 20mA max.

Figure 1. Application circuits for 0.6V output and 1.2V output voltages





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TYPICAL APPLICATION

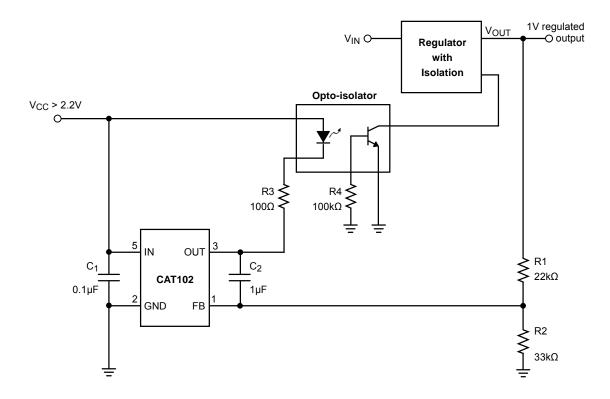


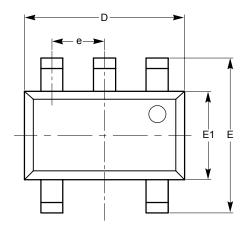
Figure 2. Opto-Feedback Application Circuit

In order to allow proper operation of the optocoupler and the CAT102, the supply voltage V_{CC} must be greater than 2.2V.



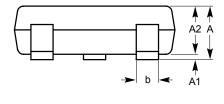
PACKAGE OUTLINES

TSOT-23 5-Lead (TD)

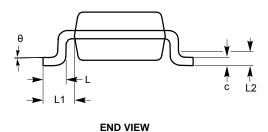


TOP VIEW

SYMBOL	MIN	MAX	
Α			1.00
A1	0.01	0.05	0.10
A2	0.80	0.87	0.90
b	0.30		0.45
С	0.12	0.15	0.20
D		2.90 BSC	
Е		2.80 BSC	
E1	1.60 BSC		
е	0.95 TYP		
L	0.30	0.40	0.50
L1	0.60 REF		
L2	0.25 BSC		
θ	0°		8°



SIDE VIEW



For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

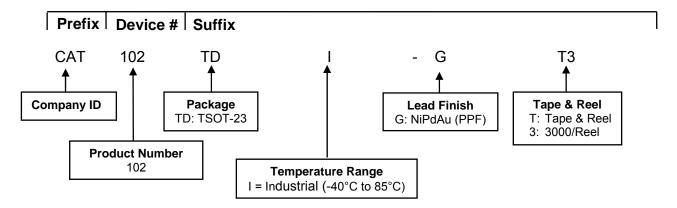
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Notes

- (1) All dimensions in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-193.



EXAMPLE OF ORDERING INFORMATION



Notes:

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free)
- (2) The device used in the above example is a CAT102TDI-GT3 (TSOT-23, Industrial Temperature, NiPdAu, Tape & Reel)

ORDERING PART NUMBER
CAT102TDI-G

REVISION HISTORY

Date	Rev.	Reason
01/29/2007	М	Added Ordering Information
06/16/2007	N	Changed package from SOT-23 to TSOT-23 Updated Features Updated Functional Diagram Updated Electrical Characteristics Updated Typical Performance Characteristics Changed termination from SnPb to NiPdAu Added MD- to document Number

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